

# RJH60F5DPQ-A0

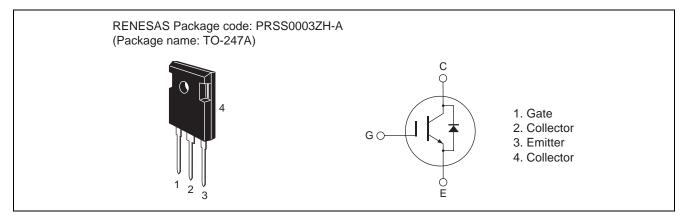
600 V - 40 A - IGBT High Speed Power Switching

R07DS0326EJ0200 Rev.2.00 Jul 22, 2011

## Features

- Low collector to emitter saturation voltage  $V_{CE(sat)} = 1.37$  V typ. (I<sub>C</sub> = 40 A, V<sub>GE</sub> = 15 V, Ta = 25°C)
- Built in fast recovery diode in one package
- Trench gate and thin wafer technology
- High speed switching  $t_r = 85$  ns typ. (at  $I_C = 30$  A,  $V_{CE} = 400$  V,  $V_{GE} = 15$  V,  $Rg = 5 \Omega$ ,  $Ta = 25^{\circ}C$ , inductive load)

### Outline



## **Absolute Maximum Ratings**

				(Tc = 25°C)	
Item		Symbol	Ratings	s Unit	
Collector to emitter voltage		V <sub>CES</sub>	600	V	
Gate to emitter voltage		V <sub>GES</sub>	±30	V	
Collector current	Tc = 25 °C	lc	80	А	
	Tc = 100 °C	lc	40	А	
Collector peak current		ic(peak) <sup>Note1</sup>	160	А	
Collector to emitter diode forward peak current		i <sub>DF</sub> (peak) Note2	100	А	
Collector dissipation		Pc	260.4	W	
Junction to case thermal impedance (IGBT)		өј-с	0.48	°C/W	
Junction to case thermal impedance (Diode)		θj-cd	2.0	°C/W	
Junction temperature		Tj	150	°C	
Storage temperature		Tstg	-55 to +150	°C	
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Notes: 1. Pulse width limited by safe operating area.

2.  $PW \leq 5~\mu s,~duty~cycle \leq 1\%$ 



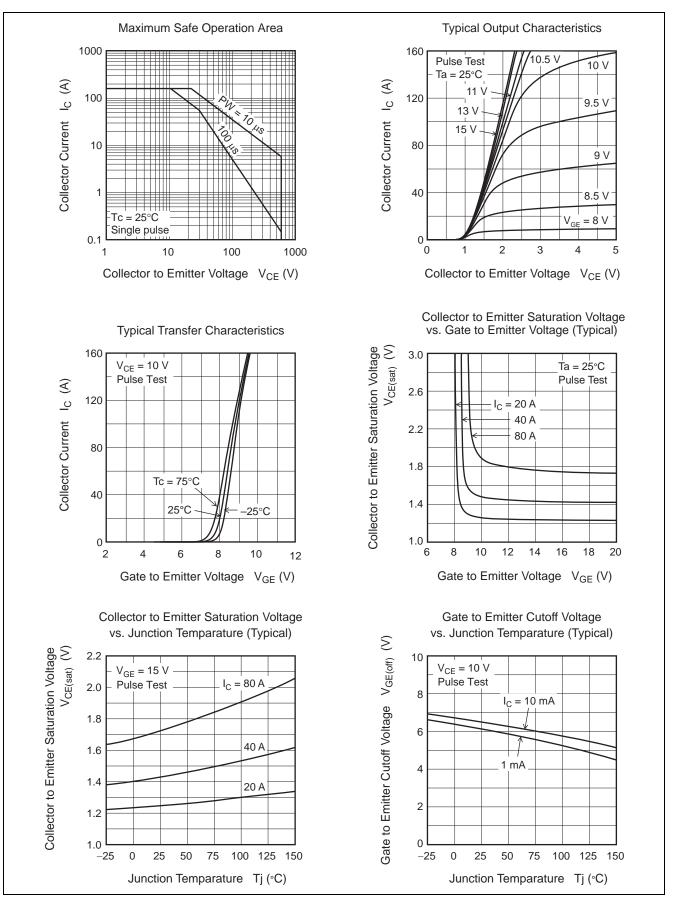
# **Electrical Characteristics**

						(Tj = 25°C)
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Zero gate voltage collector current	I <sub>CES</sub>	_	_	100	μΑ	$V_{CE} = 600V, V_{GE} = 0$
Gate to emitter leak current	I <sub>GES</sub>		—	±1	μΑ	$V_{GE} = \pm 30 \text{ V}, \text{ V}_{CE} = 0$
Gate to emitter cutoff voltage	V <sub>GE(off)</sub>	4		8	V	$V_{CE} = 10 \text{ V}, I_{C} = 1 \text{ mA}$
Collector to emitter saturation voltage	V <sub>CE(sat)</sub>		1.37	1.8	V	$I_{C} = 40 \text{ A}, V_{GE} = 15 \text{ V}^{Note3}$
	V <sub>CE(sat)</sub>		1.7		V	$I_{C} = 80 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$
Input capacitance	Cies		2780		pF	$V_{CE} = 25 V$ $V_{GE} = 0 V$ $f = 1 MHz$
Output capacitance	Coes		122		pF	
Reverse transfer capacitance	Cres		43		pF	
Switching time	t <sub>d(on)</sub>		53		ns	$\label{eq:CE} \begin{array}{l} I_C = 30 \text{ A}, \\ V_{CE} = 400 \text{ V},  V_{GE} = 15 \text{ V} \\ \text{Rg} = 5 \ \Omega^{\text{ Note3}}, \\ \text{Inductive load} \end{array}$
	tr		145		ns	
	t <sub>d(off)</sub>		105		ns	
	t <sub>f</sub>		85		ns	
C-E diode forward voltage	V <sub>ECF1</sub>		1.2	2.1	V	$I_F = 20 \text{ A}^{\text{Note3}}$
	V <sub>ECF2</sub>		1.5		V	$I_F = 40 \text{ A}^{\text{Note3}}$
C-E diode reverse recovery time	t <sub>rr</sub>		90		ns	I <sub>F</sub> = 20 A
						di <sub>F</sub> /dt = 100 A/µs

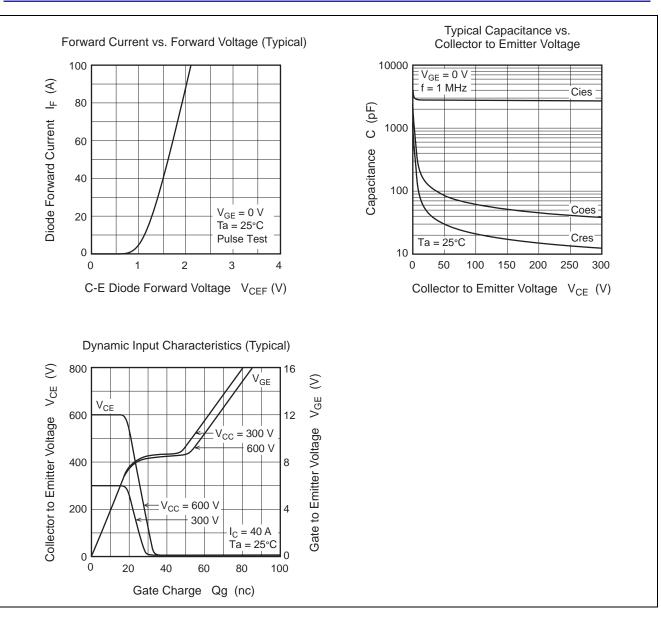
Notes: 3. Pulse test



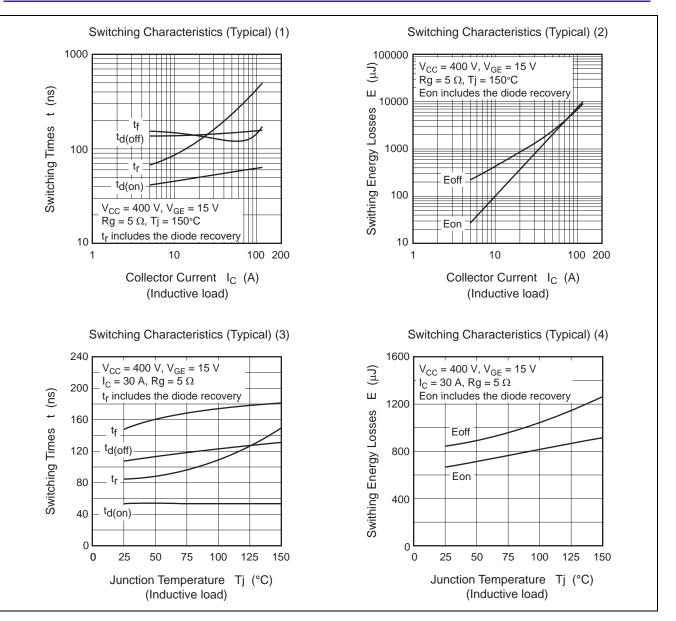
#### **Main Characteristics**



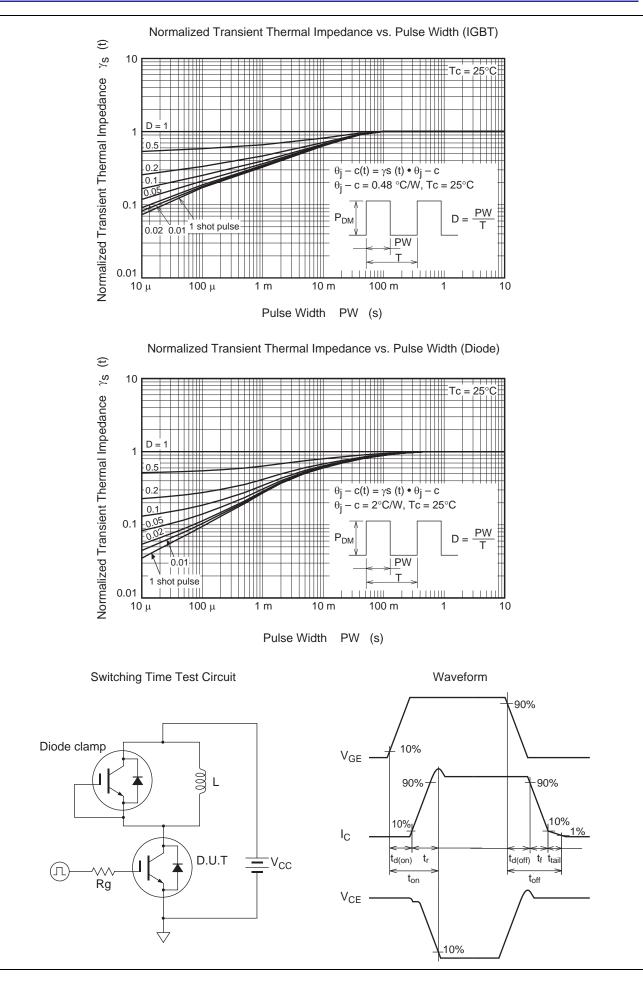






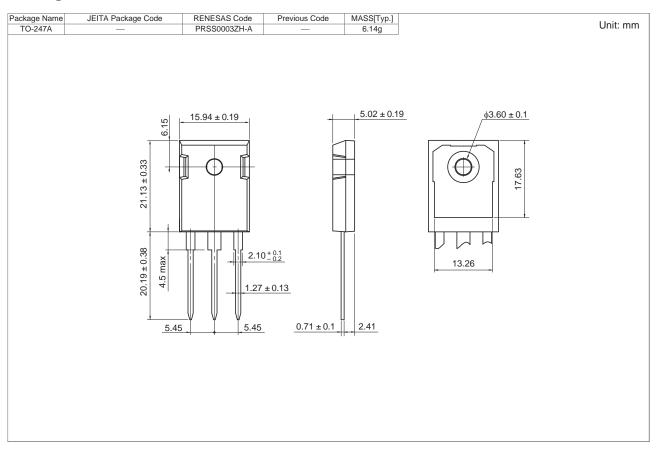








#### **Package Dimensions**



## **Ordering Information**

Orderable Part Number	Quantity	Shipping Container	
RJH60F5DPQ-A0-T0	240 pcs	Box (Tube)	



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